## NSN 5961-00-485-5089

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-485-5089 **Inclosure Material:** Metal **Overall Length:** 0.468 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Internal Junction Configuration:** Pnp **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 5.5 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 2.00 amperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug **Specification Data:** 80131-release5569 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No